

ETR2902-005

Transient Voltage Suppressor (TVS)

■GENERAL DESCRIPTION

Two elements in USP-3 package (Anode Common) High ESD

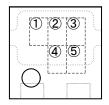
■ ABSOLUTE MAXIMUM RATINGS

Ta=25°C

PARAMETER	SYMBOL	RATINGS	UNITS	
Peak Pulse Power (*1)	Ppk	70	W	
Power Dissipation	Pd	120	mW	
Fower Dissipation	Fu	1000(*2)	11100	
Junction Temperature	Tj	150	°C	
Storage Temperature Range	Tstg	-55~+150	°C	
ESD Durability (*3)(*4)	Vpp	30	kV	
Contact Discharge	νрр	30	ΝV	

- (*1): tp=8/20 μ s (*2): This is a reference data taken by using the test board.
- (*3): Test Condition IEC61000-4-2 Standard
- (*4): Criterion: No damage to device elements

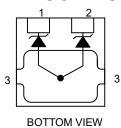
■MARKING RULE



123 : BP1(Product Number)

45 : Lot Number

■PIN CONFIGURATION



- Cathode

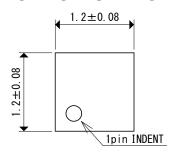
Cathode

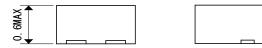
Anode

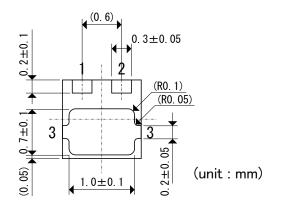
■APPLICATIONS

ESD protection

■ PACKAGING INFORMATION







USP-3 Package

■PRODUCT NAME

PRODUCT NAME	PACKAGE	ORDER UNIT		
XBP06V4E2HR-G*	USP-3	3,000/Reel		

^{*}The "-G" suffix indicates that the products are Halogen and Antimony free as well as being fully RoHS compliant.

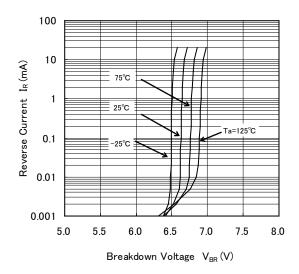
■ ELECTRICAL CHARACTERISTICS

Ta=25°C

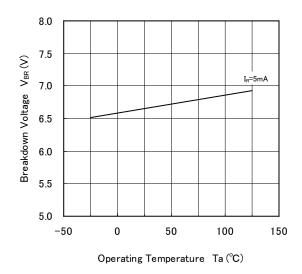
PARAMETER	SYMBOL	TEST CONDITION	LIMITS			LINITO
PARAMETER	STIVIBUL		MIN.	TYP.	MAX.	UNITS
Breakdown Voltage	V_{BR}	I _R =5mA	6.4	6.8	7.2	V
Leakage Current	I _{RM}	V _{RM} =5V	-	-	1.0	μΑ
Forward Voltage	VF	I _F =10mA	-	-	1.25	V
Inter-Terminal Capacity	Ct	V _R =0V, f=1MHz	-	40	-	pF

■TYPICAL PERFORMANCE CHARACTERISTICS

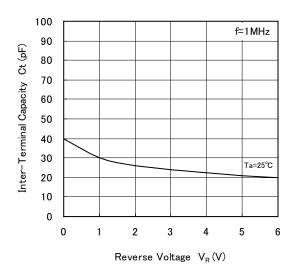
(1) Reverse Current vs. Breakdown Voltage



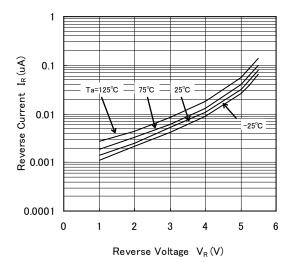
(3) Breakdown Voltage vs. Operating Temperature



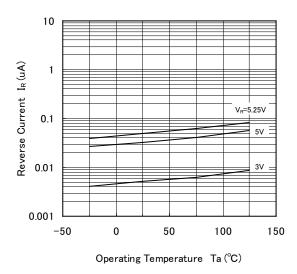
(5) Inter-Terminal Capacity vs. Reverse Voltage



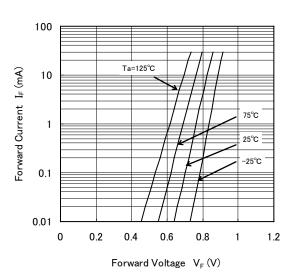
(2) Reverse Current vs. Reverse Voltage



(4) Reverse Current vs. Operating Temperature



(6) Forward Current vs. Forward Voltage



■PACKAGING INFORMATION

USP-3 Power Dissipation

Power dissipation data for the USP-3 is shown in this page. The value of power dissipation varies with the mount board conditions. Please use this data as one of reference data taken in the described condition.



Condition: Mount on a board
Ambient: Natural convection
Soldering: Lead (Pb) free

Board: Dimensions 40 x 40 mm (1600 mm² in one side)

Copper (Cu) traces occupy 50% of the board area

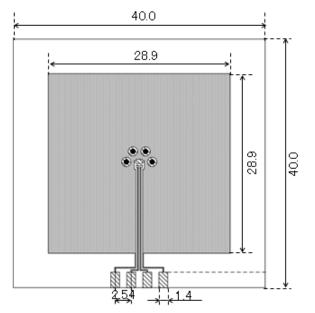
in top and back faces.

Package heat-sink is tied to the copper traces.

Material: Glass Epoxy (FR-4)

Thickness: 1.6 mm

Through-hole: 4 x 0.8 Diameter

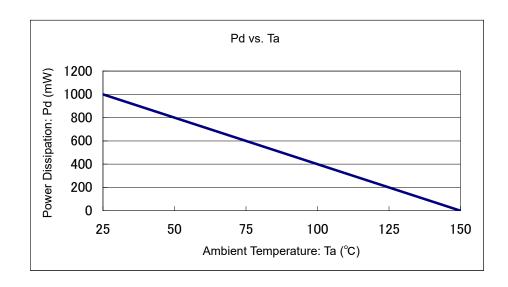


Evaluation Board (Unit: mm)

2. Power Dissipation vs. Ambient temperature

Board Mount (Tj max = 150°C)

Ambient Temperature (°C)	Power Dissipation Pd (mW)	Thermal Resistance (°C/W)		
25	1000	125.00		
150	0	125.00		



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